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Publications

PUBLICATIONS

- **Application-driven synthesis and characterization of hexagonal boron nitride deposited on metals and carbon nanotubes** *2D MATERIALS*
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- **Contact Engineering High-Performance n-Type MoTe₂ Transistors.** *Nano letters*
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- **3D Monolithic Stacked 1T1R cells using Monolayer MoS₂ FET and hBN RRAM Fabricated at Low (150 degrees C) Temperature**
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